SIEMENS

Data sheet

6AU1425-2AA00-0AA0



SIMOTION Drive-based Control Unit D425-2 DP; programmable motion controller; BASIC performance; interfaces: 12 DI, 16 DI/DO, 4 DRIVE-CLiQ, 2 PROFIBUS, 3 ethernet, 2 USB, 1 option slot; incl. dual fan / battery module and battery

SIMOTION product brand name product type designation D425-2 DP Performance class for motion control system **BASIC Performance** Version of the motion control system Multiple-axis system PLC and motion control performance number of axes / maximum 16 Minimum PROFIBUS cycle clock 1 ms Minimum interpolator cycle clock 0.5 ms Minimum servo cycle clock 0.5 ms Integrated drive control / header Maximum number of axes for integrated drive control servo 6 vector 6 V/f Alternative control modes; drive control based on SINAMICS S120 note CU320-2, firmware version V4.x/V5.x Memory RAM (work memory) 78 Mbyte Additional RAM work memory for Java applications 20 Mbyte RAM disk (load memory) 38 Mbyte Retentive memory 364 kbyte Persistent memory (user data on CF) 1.5 Gbyte Communication Interfaces • DRIVE-CLiQ 4 USB 2 Industrial Ethernet 3 PROFIBUS - note Equidistant and isochronous; Can be configured as master or slave PROFINET 0 General technical data Fan Double fan/battery module included in scope of delivery DC supply voltage 24 V • rated value 20.4 V minimum • maximum 28.8 V consumed current / typical note with no load on inputs/outputs, no 24 V supply via DRIVE-CLiQ and PROFIBUS interface Making current, typ. 5 A 17 W

Power loss, typ.

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Ambient temperature, during	
 long-term storage 	-25 +55 °C
transport	-40 +70 °C
operation	0 55 °C
— note	Maximum installation altitude 4000 m (13124 ft) above sea level. Above
	an altitude of 2000 m (6562 ft), the maximum ambient temperature
	decreases by 7 °C (12.6 °F) per 1000 m (3281 ft).
Relative humidity	
during operation	5 95 %
 without condensation, tested acc. to IEC 60068-2- 	Wert fehlt
38	
Product property / Conformal coating	No
Resistance	
• to biologically active substances, / conformity acc. to	No
EN 60721-3-3	
 to chemically active substances, / conformity acc. to 	No
EN 60721-3-3	
Air pressure	620 1 060 hPa
Degree of protection	IP20 / UL open type
height	380 mm
width	50 mm
• depth	270 mm
Depth / Note	When the spacer is removed 230 mm (9.05 in) deep
net weight	3 700 g
Digital inputs / header	
number of digital inputs	12
DC input voltage	
• rated value	24 V
• for signal "1"	15 30 V
• for signal "0"	-3 +5 V
Electrical isolation	Yes
• note	Yes, in groups of 6
Current consumption for "1" signal level, typ.	9 mA
Input delay time for	
Input delay time for • signal "0" → "1", typ.	50 μs
Input delay time for	
Input delay time for • signal "0" → "1", typ.	50 μs
Input delay time for • signal "0" → "1", typ. • signal "1" → "0", typ.	50 μs
Input delay time for • signal "0" → "1", typ. • signal "1" → "0", typ. Digital inputs/outputs / header	50 μs 150 μs
Input delay time for • signal "0" → "1", typ. • signal "1" → "0", typ. Digital inputs/outputs / header Number of digital I/Os	50 μs 150 μs
Input delay time for • signal "0" → "1", typ. • signal "1" → "0", typ. Digital inputs/outputs / header Number of digital I/Os	50 μs 150 μs 16 can be parameterized - as DI - as DO - as probe input (max. 16) - as
Input delay time for • signal "0" → "1", typ. • signal "1" → "0", typ. Digital inputs/outputs / header Number of digital I/Os Parameterization possibility of the digital I/Os	50 μs 150 μs 16 can be parameterized - as DI - as DO - as probe input (max. 16) - as
Input delay time for • signal "0" → "1", typ. • signal "1" → "0", typ. Digital inputs/outputs / header Number of digital I/Os Parameterization possibility of the digital I/Os If used as an input / header	50 μs 150 μs 16 can be parameterized - as DI - as DO - as probe input (max. 16) - as
Input delay time for • signal "0" → "1", typ. • signal "1" → "0", typ. Digital inputs/outputs / header Number of digital I/Os Parameterization possibility of the digital I/Os If used as an input / header DC input voltage	50 μs 150 μs 16 can be parameterized - as DI - as DO - as probe input (max. 16) - as cam output (max. 8)
Input delay time for • signal "0" → "1", typ. • signal "1" → "0", typ. Digital inputs/outputs / header Number of digital I/Os Parameterization possibility of the digital I/Os If used as an input / header DC input voltage • rated value • for signal "1"	50 μs 150 μs 16 can be parameterized - as DI - as DO - as probe input (max. 16) - as cam output (max. 8)
Input delay time for • signal "0" → "1", typ. • signal "1" → "0", typ. Digital inputs/outputs / header Number of digital I/Os Parameterization possibility of the digital I/Os If used as an input / header DC input voltage • rated value	50 μs 150 μs 16 can be parameterized - as DI - as DO - as probe input (max. 16) - as cam output (max. 8) 24 V 15 30 V
Input delay time for • signal "0" → "1", typ. • signal "1" → "0", typ. Digital inputs/outputs / header Number of digital I/Os Parameterization possibility of the digital I/Os If used as an input / header DC input voltage • rated value • for signal "1" • for signal "0" Electrical isolation	50 μs 150 μs 16 can be parameterized - as DI - as DO - as probe input (max. 16) - as cam output (max. 8) 24 V 15 30 V -3 +5 V No
Input delay time for • signal "0" → "1", typ. • signal "1" → "0", typ. Digital inputs/outputs / header Number of digital I/Os Parameterization possibility of the digital I/Os If used as an input / header DC input voltage • rated value • for signal "1" • for signal "0" Electrical isolation Current consumption for "1" signal level, typ.	50 μs 150 μs 16 can be parameterized - as DI - as DO - as probe input (max. 16) - as cam output (max. 8) 24 V 15 30 V -3 +5 V
Input delay time for • signal "0" → "1", typ. • signal "1" → "0", typ. Digital inputs/outputs / header Number of digital I/Os Parameterization possibility of the digital I/Os If used as an input / header DC input voltage • rated value • for signal "1" • for signal "0" Electrical isolation Current consumption for "1" signal level, typ. Input delay time for	50 μs 150 μs 16 can be parameterized - as DI - as DO - as probe input (max. 16) - as cam output (max. 8) 24 V 15 30 V -3 +5 V No 9 mA
Input delay time for • signal "0" → "1", typ. • signal "1" → "0", typ. Digital inputs/outputs / header Number of digital I/Os Parameterization possibility of the digital I/Os If used as an input / header DC input voltage • rated value • for signal "1" • for signal "0" Electrical isolation Current consumption for "1" signal level, typ. Input delay time for • signal "0" → "1", typ.	50 μs 150 μs 16 can be parameterized - as DI - as DO - as probe input (max. 16) - as cam output (max. 8) 24 V 15 30 V -3 +5 V No 9 mA 5 μs
Input delay time for • signal "0" → "1", typ. • signal "1" → "0", typ. Digital inputs/outputs / header Number of digital I/Os Parameterization possibility of the digital I/Os If used as an input / header DC input voltage • rated value • for signal "1" • for signal "0" Electrical isolation Current consumption for "1" signal level, typ. Input delay time for • signal "0" → "1", typ. • signal "1" → "0", typ.	50 μs 150 μs 16 can be parameterized - as DI - as DO - as probe input (max. 16) - as cam output (max. 8) 24 V 15 30 V -3 +5 V No 9 mA 5 μs 50 μs
Input delay time for • signal "0" → "1", typ. • signal "1" → "0", typ. Digital inputs/outputs / header Number of digital I/Os Parameterization possibility of the digital I/Os If used as an input / header DC input voltage • rated value • for signal "1" • for signal "0" Electrical isolation Current consumption for "1" signal level, typ. Input delay time for • signal "0" → "1", typ. • signal "1" → "0", typ. Measuring input / reproducibility	50 μ s 150 μ s 16 can be parameterized - as DI - as DO - as probe input (max. 16) - as cam output (max. 8) 24 V 15 30 V -3 +5 V No 9 mA 5 μ s 50 μ s 5 μ s
Input delay time for • signal "0" → "1", typ. • signal "1" → "0", typ. Digital inputs/outputs / header Number of digital I/Os Parameterization possibility of the digital I/Os If used as an input / header DC input voltage • rated value • for signal "1" • for signal "0" Electrical isolation Current consumption for "1" signal level, typ. Input delay time for • signal "0" → "1", typ. • signal "1" → "0", typ. Measuring input / reproducibility Measuring input / resolution	50 μs 150 μs 16 can be parameterized - as DI - as DO - as probe input (max. 16) - as cam output (max. 8) 24 V 15 30 V -3 +5 V No 9 mA 5 μs 50 μs
Input delay time for • signal "0" → "1", typ. • signal "1" → "0", typ. Digital inputs/outputs / header Number of digital I/Os Parameterization possibility of the digital I/Os If used as an input / header DC input voltage • rated value • for signal "1" • for signal "0" Electrical isolation Current consumption for "1" signal level, typ. Input delay time for • signal "0" → "1", typ. • signal "1" → "0", typ. Measuring input / reproducibility	50 μ s 150 μ s 16 can be parameterized - as DI - as DO - as probe input (max. 16) - as cam output (max. 8) 24 V 15 30 V -3 +5 V No 9 mA 5 μ s 50 μ s 5 μ s
Input delay time for • signal "0" → "1", typ. • signal "1" → "0", typ. Digital inputs/outputs / header Number of digital I/Os Parameterization possibility of the digital I/Os If used as an input / header DC input voltage • rated value • for signal "1" • for signal "0" Electrical isolation Current consumption for "1" signal level, typ. Input delay time for • signal "0" → "1", typ. • signal "1" → "0", typ. Measuring input / reproducibility Measuring input / resolution	50 μ s 150 μ s 16 can be parameterized - as DI - as DO - as probe input (max. 16) - as cam output (max. 8) 24 V 15 30 V -3 +5 V No 9 mA 5 μ s 50 μ s 5 μ s
Input delay time for • signal "0" → "1", typ. • signal "1" → "0", typ. Digital inputs/outputs / header Number of digital I/Os Parameterization possibility of the digital I/Os If used as an input / header DC input voltage • rated value • for signal "1" • for signal "0" Electrical isolation Current consumption for "1" signal level, typ. Input delay time for • signal "0" → "1", typ. • signal "1" → "0", typ. Measuring input / reproducibility Measuring input / resolution If used as an output / header	50 μ s 150 μ s 16 can be parameterized - as DI - as DO - as probe input (max. 16) - as cam output (max. 8) 24 V 15 30 V -3 +5 V No 9 mA 5 μ s 50 μ s 5 μ s
Input delay time for • signal "0" → "1", typ. • signal "1" → "0", typ. Digital inputs/outputs / header Number of digital I/Os Parameterization possibility of the digital I/Os If used as an input / header DC input voltage • rated value • for signal "1" • for signal "0" Electrical isolation Current consumption for "1" signal level, typ. Input delay time for • signal "0" → "1", typ. • signal "1" → "0", typ. Measuring input / reproducibility Measuring input / resolution If used as an output / header Load voltage	$50~\mu s$ 16 can be parameterized - as DI - as DO - as probe input (max. 16) - as cam output (max. 8) $24~V$ $15~~30~V$ $-3~~+5~V$ No $9~mA$ $5~\mu s$ $50~\mu s$ $5~\mu s$ $1~\mu s$
Input delay time for	$50 \mu s$ $150 \mu s$ 16 can be parameterized - as DI - as DO - as probe input (max. 16) - as cam output (max. 8) 24 V 15 30 V -3 +5 V No 9 mA 5 μs 50 μs 5 μs 1 μs
Input delay time for	$150 \mu s$ $150 \mu s$ 16 can be parameterized - as DI - as DO - as probe input (max. 16) - as cam output (max. 8) 24 V $15 \dots 30 V$ $-3 \dots +5 V$ No $9 mA$ $5 \mu s$ $50 \mu s$ $5 \mu s$ $1 \mu s$
Input delay time for	16 can be parameterized - as DI - as DO - as probe input (max. 16) - as cam output (max. 8) 24 V 15 30 V -3 +5 V No 9 mA 5 μs 50 μs 5 μs 1 μs 24 V 20.4 V 28.8 V No
Input delay time for	50 μs 150 μs 16 can be parameterized - as DI - as DO - as probe input (max. 16) - as cam output (max. 8) 24 V 15 30 V -3 +5 V No 9 mA 5 μs 50 μs 5 μs 1 μs 24 V 20.4 V 28.8 V No 500 mA
Input delay time for	16 can be parameterized - as DI - as DO - as probe input (max. 16) - as cam output (max. 8) 24 V 15 30 V -3 +5 V No 9 mA 5 μs 50 μs 5 μs 1 μs 24 V 20.4 V 28.8 V No
Input delay time for	50 μs 150 μs 16 can be parameterized - as DI - as DO - as probe input (max. 16) - as cam output (max. 8) 24 V 15 30 V -3 +5 V No 9 mA 5 μs 50 μs 5 μs 1 μs 1 μs
Input delay time for	50 μs 150 μs 16 can be parameterized - as DI - as DO - as probe input (max. 16) - as cam output (max. 8) 24 V 15 30 V -3 +5 V No 9 mA 5 μs 50 μs 5 μs 1 μs 24 V 20.4 V 28.8 V No 500 mA 2 mA
Input delay time for	50 μs 150 μs 16 can be parameterized - as DI - as DO - as probe input (max. 16) - as cam output (max. 8) 24 V 15 30 V -3 +5 V No 9 mA 5 μs 50 μs 5 μs 1 μs 1 μs

ullet signal "1" \to "0", max. 150 µs Data for Vcc = 24 V; load 48 Ohm; "1" = 90 % VOut, "0" = 10 % VOut - note Cam output reproducibility resolution 1 µs Switching frequency of the outputs for • resistive load, max. 4 kHz • inductive load, max. 2 Hz • lamp load, max. 11 Hz Short-circuit protection Yes

Additional technical data

Back-up of non-volatile data

• of retentive data

• of real-time clock, min.

note

Charging time, typ.

note

Approvals

USA

Canada

Australia

Korea

• Russia, Belarus and Kazakhstan

unlimited buffer duration

longer buffer duration of the real-time clock using a battery inserted in

the double fan/battery module

A few minutes

cULus cULus

RCM (formerly C-Tick)

KCC EAC

